

HA17431VPJ/PJ/PAJ/FPJ/FPAJ/PNAJ/UPA, **HA17432UPA** Shunt Regulator

REJ03D0892-0100 Rev.1.00 Apr 03, 2007

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Description

The HA17431 series is temperature-compensated variable shunt regulators. The main application of these products is in voltage regulators that provide a variable output voltage. The on-chip high-precision reference voltage source can provide $\pm 1\%$ accuracy in the V versions, which have a V_{KA} max of 16 volts.

Features

- The V versions provide 2.500 V $\pm 1\%$ at Ta = 25°C •
- The reference voltage has a low temperature coefficient
- The UPAKV miniature packages are optimal for use on high mounting density circuit boards •

Block Diagram



Application Circuit Example







Ordering Information

		Refere	nce voltage (at 2	25°C)		
	Item	Normal Version ±4% 2.395V to 2.495V to 2.595V	A Version ±2.2% 2.440V to 2.495V to 2.550V	V Version ±1% 2.475V to 2.500V to 2.525V	Package Code (Package Name)	Operating Temperature Range
	HA17431FPAJ		0		PRSP0008DE-B (FP-8DGV)	
	HA17431FPJ	0			PRSP0008DE-B (FP-8DGV)	
Car use	HA17431PAJ		0		PRSS0003DC-A (TO-92MODV)	–40 to +85°C
Caluse	HA17431PJ	0			PRSS0003DC-A (TO-92MODV)	-40 to +85 C
	HA17431PNAJ		0		PRSS0003DA-A (TO-92V)	
	HA17431VPJ			0	PRSS0003DA-A (TO-92V)	
Industrial	HA17431UPA		0	0	PLZZ0004CA-A (UPAKV)	–20 to +85°C
use	HA17432UPA		0		PLZZ0004CA-A (UPAKV)	-20 10 +05 C

Pin Arrangement



Absolute Maximum Ratings

					(Ta	= 25°C)
			Ratings			
Item	Symbol	HA17431VPJ	HA17431UPA	HA17432UPA	Unit	Notes
Cathode voltage	V _{KA}	16	40	40	V	1
Continuous cathode current	Ι _κ	-50 to +50	-100 to +150	-100 to +150	mA	
Reference input current	Iref	–0.05 to +10	–0.05 to +10	-0.05 to +10	mA	
Power dissipation	PT	500 * ²	800 *5	800 * ⁵	mW	2, 5
Operating temperature range	Topr	-40 to +85	-20 to +85	-20 to +85	°C	
Storage temperature	Tstg	–55 to +150	-55 to +150	-55 to +150	°C	

Item	Symbol	HA17431PNAJ	HA17431PJ/PAJ	HA17431FPJ/FPAJ	Unit	Notes
Cathode voltage	V _{KA}	40	40	40	V	1
Continuous cathode current	Ι _κ	–100 to +150	-100 to +150	-100 to +150	mA	
Reference input current	Iref	–0.05 to +10	–0.05 to +10	–0.05 to +10	mA	
Power dissipation	PT	500 * ²	800 * ³	500 * ⁴	mW	2, 3, 4
Operating temperature range	Topr	-40 to +85	-40 to +85	-40 to +85	°C	
Storage temperature	Tstg	–55 to +150	-55 to +150	-55 to +125	°C	

Notes: 1. Voltages are referenced to anode.

2. Ta \leq 25°C. If Ta > 25°C, derate by 4.0 mW/°C.

3. Ta \leq 25°C. If Ta > 25°C, derate by 6.4 mW/°C.

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- 50 mm × 50 mm × 1.5mmt glass epoxy board (5% wiring density), Ta ≤ 25°C. If Ta > 25°C, derate by 5 mW/°C.
- 5. 15 mm × 25 mm × 0.7mmt alumina ceramic board, Ta \leq 25°C. If Ta > 25°C, derate by 6.4 mW/°C.

Electrical Characteristics

HA17431VPJ

(Ta =	25°C. Iv	x = 10 mA
(1a –	$25 C, 1_{\rm K}$	(-10 mm)

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	Notes
Reference voltage	Vref	2.475	2.500	2.525	V	V _{KA} = Vref	
Reference voltage	Vref(dev)	—	10	_	mV	V _{KA} = Vref,	1
temperature deviation						Ta = –20°C to +85°C	
Reference voltage	∆Vref/∆Ta	—	±30	_	ppm/°C	V _{KA} = Vref,	
temperature coefficient						0°C to 50°C gradient	
Reference voltage regulation	$\Delta V ref / \Delta V_{KA}$	—	2.0	3.7	mV/V	V _{KA} = Vref to 16 V	
Reference input current	Iref	—	2	6	μA	R_1 = 10 k Ω , R_2 = ∞	
Reference current	Iref(dev)	_	0.5	_	μA	R ₁ = 10 kΩ, R ₂ = ∞,	
temperature						Ta = –20°C to +85°C	
deviation							
Minimum cathode current	Imin	—	0.4	1.0	mA	V _{KA} = Vref	2
Off state cathode current	loff	—	0.001	1.0	μA	V _{KA} = 16 V, Vref = 0 V	
Dynamic impedance	Z _{KA}	_	0.2	0.5	Ω	V _{KA} = Vref,	
						$I_{\rm K}$ = 1 mA to 50 mA	

HA17431PJ/PAJ/FPJ/FPAJ/PNAJ/UPA, HA17432UPA

 $(Ta = 25^{\circ}C, I_{K} = 10 \text{ mA})$

							(/ K	
Item	Symbol	Min	Тур	Max	Unit	Tes	t Conditions	Notes
Reference voltage	Vref	2.440	2.495	2.550	V	V _{KA} = Vref		А
		2.395	2.495	2.595				Normal
Reference voltage	Vref(dev)		11	(30)	mV	V _{KA} = Vref	Ta =	1, 3, 4
temperature deviation							–20°C to +85°C	
			5	(17)			Ta = 0°C to +70°C	1, 3, 5
Reference voltage	$\Delta Vref/\Delta V_{KA}$	Ι	1.4	3.7	mV/V	V _{KA} = Vref t	o 10 V	
regulation		—	1	2.2		V _{KA} = 10 V	to 40 V	
Reference input current	Iref	-	3.8	6	μA	R ₁ = 10 kΩ	, R ₂ = ∞	
Reference current	Iref(dev)	Ι	0.5	(2.5)	μA	R ₁ = 10 kΩ	, R₂ = ∞,	3
temperature deviation		R .				Ta = 0°C to	+70°C	
Minimum cathode current	Imin		0.4	1.0	mA	V _{KA} = Vref		2
Off state cathode current	loff	—	0.001	1.0	μA	V _{KA} = 40 V, Vref = 0 V		
Dynamic impedance	ZKA	—	0.2	0.5	Ω	V _{KA} = Vref,		
						$I_{\rm K}$ = 1 mA to	o 100 mA	

Notes: 1. Vref(dev) = Vref(max) – Vref(min)



- 2. Imin is given by the cathode current at Vref = $Vref_{(IK=10mA)} 15 \text{ mV}$.
- 3. The maximum value is a design value (not measured).
- 4. HA17431PJ/PAJ/FPJ/FPAJ/PNAJ
- 5. HA17431UPA, HA17432UPA

UPAKV Marking Patterns

The marking patterns shown below are used on UPAKV products. Note that the product code and mark pattern are different. The pattern is laser-printed.



Notes: 1. Boxes (1) to (5) in the figures show the position of the letters or numerals, and are not actually marked on the package.

2. The letters (1) and (2) show the product specific mark pattern.

Product	(1)	(2)
HA17431UPA	4	В
HA17432UPA	4	F

- 3. The letter (3) shows the production year code (the last digit of the year).
- 4. The letter (4) shows the production month code (see table below).

Production month	Jan.	Feb.	Mar.	Apr.	May.	Jun.	Jul.	Aug.	Sep.	Oct.	Nov.	Dec.
Marked code	А	В	С	D	E	F	G	Ŧ	J	К	L	М

5. The letter (5) shows manufacturing code.

Characteristics Curves

HA17431VPJ











Application Examples

As shown in the figure on the right, this IC operates as an inverting amplifier, with the REF pin as input pin. The openloop voltage gain is given by the reciprocal of "reference voltage deviation by cathode voltage change" in the electrical specifications, and is approximately 50 to 60 dB. The REF pin has a high input impedance, with an input current Iref of 3.8 μ A Typ (V version: Iref = 2 μ A Typ). The output impedance of the output pin K (cathode) is defined as dynamic impedance Z_{KA}, and Z_{KA} is low (0.2 Ω) over a wide cathode current range. A (anode) is used at the minimum potential, such as ground.



Figure 1 Operation Diagram

Application Hints

No.	Application Example	Description
1	Reference voltage generation circuit Vin $\bigcirc - & \bigcirc $	This is the simplest reference voltage circuit. The value of the resistance R is set so that cathode current $I_K \ge 1$ mA. Output is fixed at Vout $\cong 2.5$ V. The external capacitor C_L ($C_L \ge 3.3 \mu$ F) is used to prevent oscillation in normal applications.
2	Variable output shunt regulator circuit $Vin O \longrightarrow OVout$ $R_{1} \longrightarrow K$ $R_{2} \longrightarrow OVout$ $R_{2} \longrightarrow CL$ $R_{2} \longrightarrow OGND$	This is circuit 1 above with variable output provided. Here, Vout $\cong 2.5 \text{ V} \times \frac{(R_1 + R_2)}{R_2}$ Since the reference input current Iref = 3.8 µA Typ (V version: Iref = 2 µA Typ) flows through R ₁ , resistance values are chosen to allow the resultant voltage drop to be ignored.

Application Hints (cont.)



Application Hints (cont.)

No.	Application Example	Description
6	Constant voltage regulator circuit	This is a 3-pin regulator with a discrete configuration, in which the output voltage Vout = $2.5 \text{ V} \times \frac{(\text{R}_2 + \text{R}_3)}{\text{R}_3}$ R ₁ is a bias resistance for supplying the HA17431 cathode current
	GND O TTT GND O GND O TTT O Vout Cf R3 O GND	and the output transistor Q base current.
7	Discharge type constant current circuit	This circuit supplies a constant current of
		$I_L \cong \frac{2.5 \text{ V}}{R_S}$ [A] into the load. Caution is required
	2.5 V Rs	since the HA17431 cathode current is also superimposed on I_L . The requirement in this circuit is that the cathode current must be greater than Imin = 1 mA. The I_L setting therefore must be on the order of several mA or more.
	GND	niesio
8	Induction type constant current circuit v_{cc} R I_L Q	In this circuit, the load is connected on the collector side of transistor Q in circuit 7 above. In this case, the load floats from GND, but the HA17431 cathode current is not superimposed on I _L , so that I _L can be kept small (1 mA or less is possible). The constant current value is the same as for circuit 7 above: $I_L \cong \frac{2.5 \text{ V}}{\text{R}_S}$ [A]
	GND 777 777	

Design Guide for AC-DC SMPS (Switching Mode Power Supply)

1. Use of Shunt Regulator in Transformer Secondary Side Control This example is applicable to both forward transformers and flyback transformers. A shunt regulator is used on the secondary side as an error amplifier, and feedback to the primary side is provided via a photocoupler.



Figure 2 Typical Shunt Regulator/Error Amplifier

- 2. Determination of External Constants for the Shunt Regulator
 - A. DC characteristic determination

In figure 2, R_1 and R_2 are protection resistor for the light emitting diode in the photocoupler, and R_2 is a bypass resistor to feed I_K minimum, and these are determined as shown below. The photocoupler specification should be obtained separately from the manufacturer. Using the parameters in figure 2, the following formulas are obtained:

$$R_1 = \frac{V_0 - V_F - V_K}{I_F + I_B}$$
, $R_2 = \frac{V_F}{I_B}$

 V_K is the HA17431 operating voltage, and is set at around 3 V, taking into account a margin for fluctuation. R_2 is the current shunt resistance for the light emitting diode, in which a bias current I_B of around 1/5 I_F flows. Next, the output voltage can be determined by R3 and R4, and the following formula is obtained:

$$V_0 = \frac{R_3 + R_4}{R_4} \times \text{Vref, Vref} = 2.5 \text{ V Typ}$$

The absolute values of R_3 and R_4 are determined by the HA17431 reference input current Iref and the AC characteristics described in the next section. The Iref value is around 3.8 μ A Typ. (V version: 2 μ A Typ)

B. AC characteristic determination

This refers to the determination of the gain frequency characteristic of the shunt regulator as an error amplifier. Taking the configuration in figure 2, the error amplifier characteristic is as shown in figure 3.



Figure 3 HA17431 Error Amplification Characteristic

In Figure 3, the following formulas are obtained:

Gain $G_1 = G_0 \approx 50 \text{ dB to } 60 \text{ dB}$ (determined by shunt regulator)

$$G_2 = \frac{R_5}{R_3}$$

Corner frequencies $f_1 = 1/(2\pi C_1 G_0 R_3)$

 $f_2 = 1/(2\pi C_1 R_5)$

 G_0 is the shunt regulator open-loop gain; this is given by the reciprocal of the reference voltage fluctuation $\Delta V ref / \Delta V_{KA}$, and is approximately 50 dB.

3. Practical Example

Consider the example of a photocoupler, with an internal light emitting diode $V_F = 1.05$ V and $I_F = 2.5$ mA, power supply output voltage $V_2 = 5$ V, and bias resistance R_2 current of approximately 1/5 I_F at 0.5 mA. If the shunt regulator $V_K = 3$ V, the following values are found.

$$R_{1} = \frac{5V - 1.05V - 3V}{2.5mA + 0.5mA} = 316(Ω) (330Ω \text{ from E24 series})$$

$$R_{2} = \frac{1.05V}{0.5mA} = 2.1(kΩ) (2.2kΩ \text{ from E24 series})$$

Next, assume that $R_3 = R_4 = 10 \text{ k}\Omega$. This gives a 5 V output. If $R_5 = 3.3 \text{ k}\Omega$ and $C_1 = 0.022 \mu\text{F}$, the following values are found.

 $G_2 = 3.3 \text{ k}\Omega / 10 \text{ k}\Omega = 0.33 \text{ times} (-10 \text{ dB})$

 $f_1 = 1 / (2 \times \pi \times 0.022 \ \mu F \times 316 \times 10 \ k\Omega) = 2.3$ (Hz)

 $f_2 = 1 / (2 \times \pi \times 0.022 \ \mu F \times 3.3 \ k\Omega) = 2.2 \ (kHz)$

Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]		Unit: mm
UPAK	SC-62	PLZZ0004CA-A	UPAK / UPAKV	0.050g		Unit: mm
	0.53 Ma: 0.48 Max	4.5 ± 0.1 1.8 Max 0 0 0 1.5 1.5 1.5 1.5 3.0 0 0 0 0 0 0 0 0 0 0 0 0 0	1.5 ± 0.1 + 0.44 M		(0.2)	
JEITA Pack	age Code RENESAS	Code Previous Co	de MASS[Typ.]		9.	
P-SOP8-4.4:		DE-B FP-8DGV	0.19		°	NOTE) 1. DIMENSIONS**1 (Nom)'AND**2* DO NOT INCLUDE MOLD FLASH. 2. DIMENSION**3*DOES NOT INCLUDE TRIM OFFSET.
					cross section Au plating)	Reference Dimension in Millimeters Symbol Min Nom Max D 4.85 5.25 E 4.4 A2 A1 0.00 0.1 0.20 A 2.03
				ج E Detail F		$\begin{array}{c ccccccccccccccccccccccccccccccccccc$





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